Silicon NPN Triple Diffused

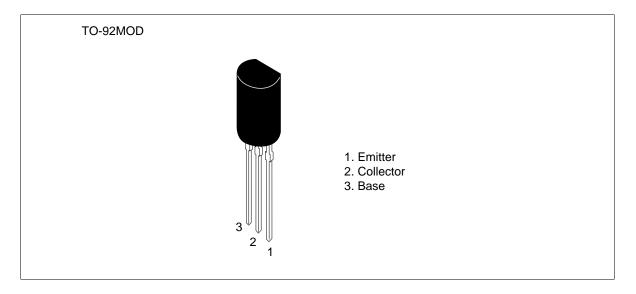
HITACHI

ADE-208-1060 (Z) 1st. Edition Mar. 2001

Application

- High frequency high voltage amplifier
- Video output

Outline



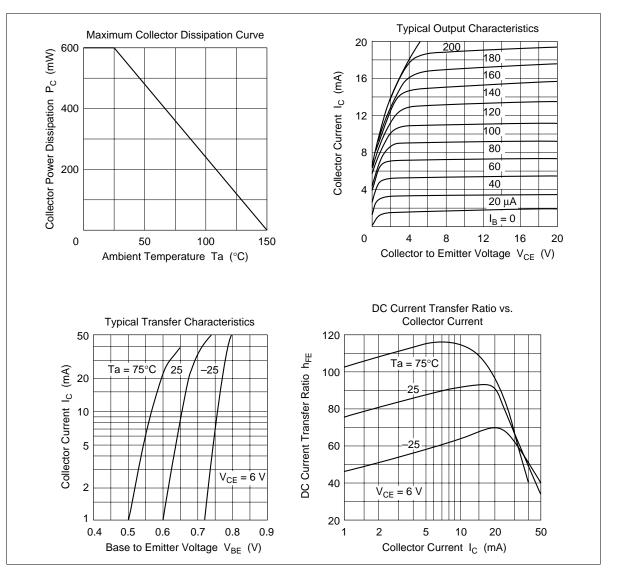


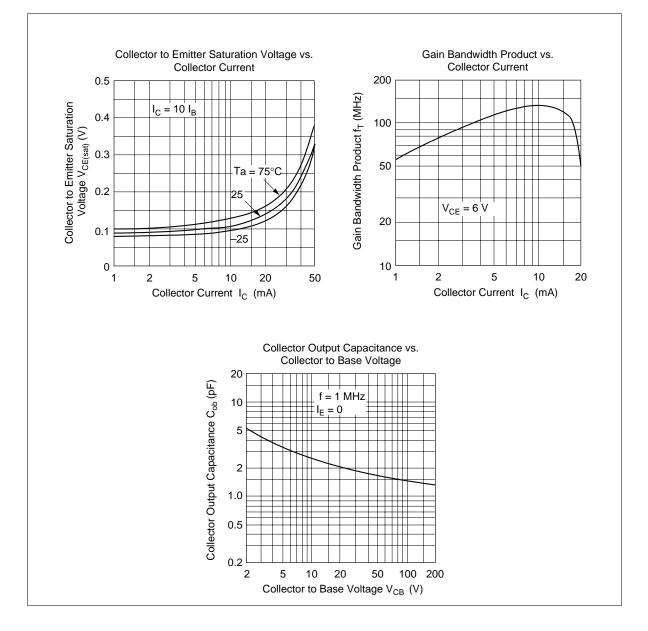
Absolute Maximum Ratings (Ta = 25° C)

ltem	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	250	V
Collector to emitter voltage	V _{CEO}	200	V
Emitter to base voltage	V _{EBO}	5	V
Collector current	Ι _c	50	mA
Collector power dissipation	Pc	600	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

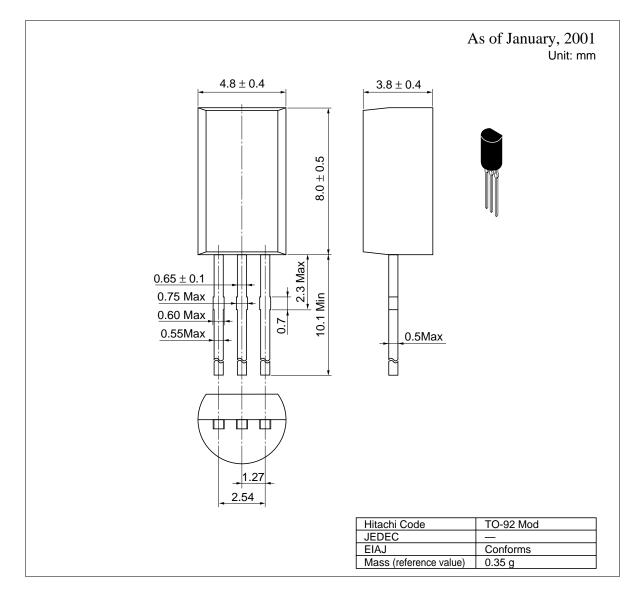
Electrical Characteristics (Ta = 25° C)

Item	Symbol	Min	Тур	Мах	Unit	Test conditions
Collector to base breakdown voltage	$V_{\rm (BR)CBO}$	250	_	-	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	200	_	_	V	$I_c = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	5	—	—	V	$I_{\rm E} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$
Collector cutoff current	I _{CEO}	—	—	1.0	μΑ	V_{ce} = 120 V, R_{Be} = ∞
DC current transfer ratio	h_{FE}	30	—	300		$V_{ce} = 6 \text{ V}, I_c = 10 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	—	—	1.0	V	$I_{c} = 10 \text{ mA}, I_{B} = 1 \text{ mA}$
Gain bandwidth product	f _T	60	130	—	MHz	$V_{ce} = 6 \text{ V}, \text{ I}_{c} = 10 \text{ mA}$
Collector output capacitance	Cob		3	4	pF	$V_{_{CB}} = 6 \text{ V}, \text{ I}_{_{E}} = 0, \text{ f} = 1 \text{ MHz}$





Package Dimensions



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